

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

50C02CH — Low-Frequency General-Purpose Amplifier Applications

Applications

· Low-frequency Amplifer, high-speed switching, small motor drive, muting circuit

Features

- · Large current capacitance
- · Low collector-to-emitter saturation voltage (resistance) R_{CE}(sat) typ.=175mΩ [I_C=0.5A, I_B=50mA]
- · Ultrasmall package facilitates miniaturization in end products
- · Small ON-resistance (Ron)

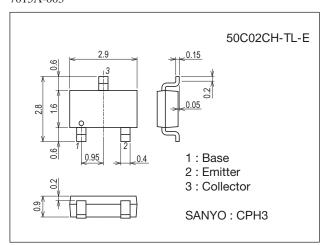
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		60	V
Collector-to-Emitter Voltage	VCEO		50	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		500	mA
Collector Current (Pulse)	ICP		1.0	Α
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² ×0.8mm)	700	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7015A-003



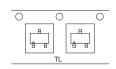
Product & Package Information

• Package : CPH3

• JEITA, JEDEC : SC-59, TO-236, SOT-23

• Minimum Packing Quantity : 3,000 pcs./reel

Packing Type: TL



Marking



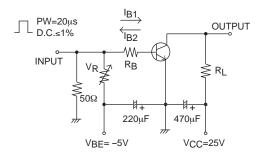
Electrical Connection



Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol	Conditions	min	typ	max	Oill
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0A			100	nA
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0A			100	nA
DC Current Gain	hFE	V _{CE} =2V, I _C =10mA	300		800	
Gain-Bandwidth Product	fŢ	V _{CE} =10V, I _C =50mA		500		MHz
Output Capacitance	Cob	VCB=10V, f=1MHz		2.8		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =100mA, I _B =10mA		50	100	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =100mA, I _B =10mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0A	60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0A	5			V
Turn-On Time	ton			30		ns
Storage Time	tstg	See specified Test Circuit.		340		ns
Fall Time	tf			55		ns

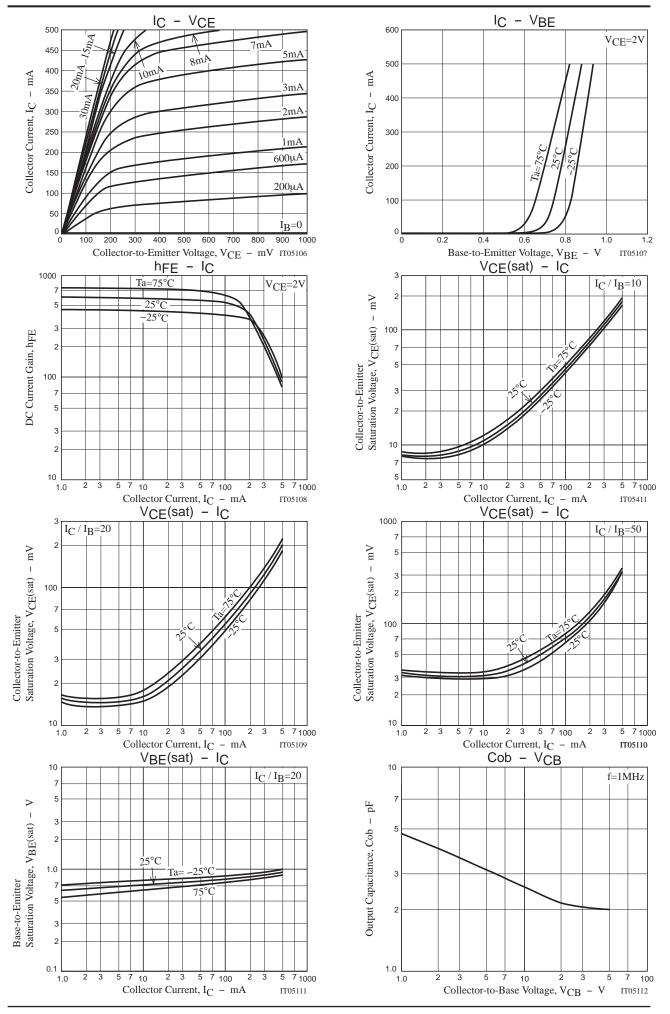
Switching Time Test Circuit

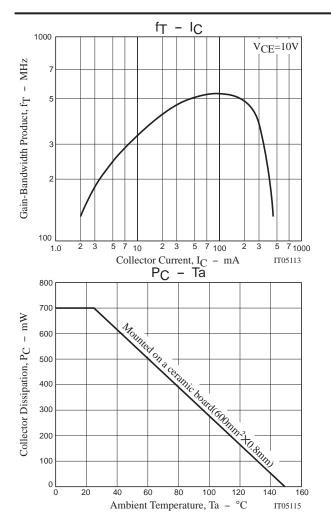


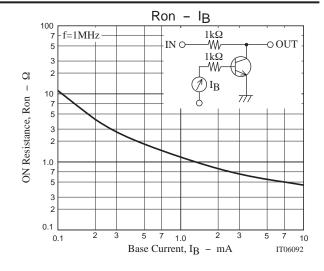
 $I_{C}=20I_{B1}=-20I_{B2}=200mA$

Ordering Information

Device	Device Package		memo	
50C02CH-TL-E CPH3		3,000pcs./reel	Pb Free	





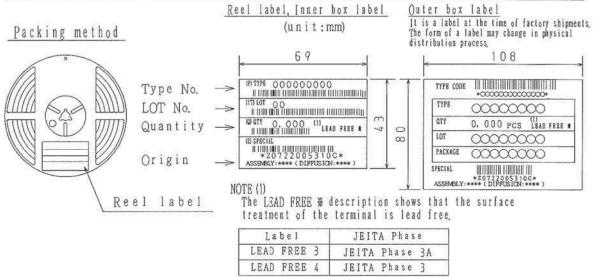


Embossed Taping Specification

50C02CH-TL-E

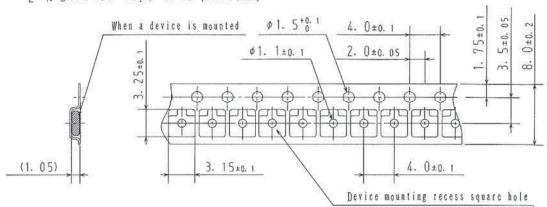
1. Packing Format

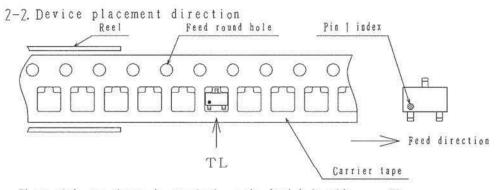
Package Name Carrier Tape	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Type	Reel	loner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
CPH3	СРНЗ	3, 000	15, 000	90, 000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) $440 \times 195 \times 210$	



2. Taping configuration

2-1. Carrier tape size (unit:mm)

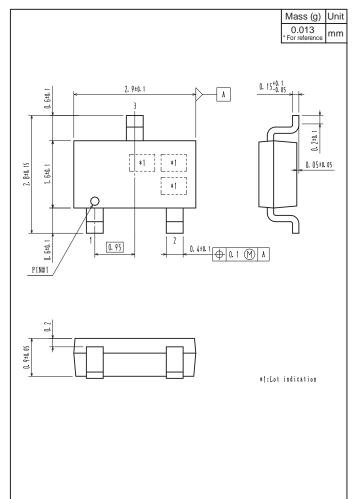




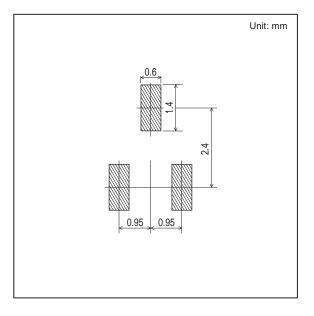
Those with one electrode terminal on the feed hole side·····TL

Outline Drawing

50C02CH-TL-E



Land Pattern Example



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